

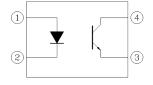
### **EL357N-G Series**

#### Features:

- · Halogens free
- Current transfer ratio
   (CTR: 50~600% at I<sub>F</sub> =5mA, V<sub>CE</sub> =5V)
- High isolation voltage between input and output (Viso=3750 V rms)
- Compact 4 Pin SOP with a 2.0 mm profile
- Pb free and RoHS compliant.
- UL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CSA approved (No. 1408633)



#### **Schematic**



### **Description**

The EL357N-G series contains an infrared emitting diode, optically coupled to a phototransistor detector.

The devices in a 4-pin small outline SMD package.

#### Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

### **Applications**

- DC-DC Converters
- Programmable controllers
- Telecommunication equipments
- Signal transmission between circuits of different potentials and impedances

Rev 4



### **EL357N-G Series**

### **Absolute Maximum Ratings (T<sub>a</sub>=25°C)**

	Parameter	Symbol	Rating	Unit
	Forward current	I <sub>F</sub>	50	mA
	Peak forward current (1us, pulse)	I <sub>FP</sub>	1	А
Input	Reverse voltage	V <sub>R</sub>	6	V
Прис	Power dissipation		70	mW
	Derating factor (about Ta=100°C)	P <sub>D</sub>	2.9	mW/°C
	Power dissipation	_	150	mW
	Derating factor (about Ta=80°C)	P <sub>C</sub>	3.7	mW/°C
Output	Collector current	Ic	50	mA
	Collector-Emitter voltage	V <sub>CEO</sub>	80	V
	Emitter-Collector voltage	V <sub>ECO</sub>	7	V
Total power dissipation		P <sub>TOT</sub>	200	mW
Isolation voltage *1		V <sub>ISO</sub>	3750	V rms
Operating	temperature	T <sub>OPR</sub>	-55 ~ +110	°C
Storage temperature		T <sub>STG</sub>	-55 ~ +125	°C
Soldering t	emperature *2	T <sub>SOL</sub>	260	°C

### **Notes**

<sup>\*1</sup> AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1 & 2 are shorted together, and pins 3 & 4 are shorted together.

<sup>\*2</sup> For 10 seconds.



### **EL357N-G Series**

## Electrical Characteristics ( $T_a$ =25°C unless specified otherwise) Input

Parameter	Symbol	Min.	Тур.*	Max.	Unit	Condition
Forward voltage	V <sub>F</sub>	-	1.2	1.4	V	I <sub>F</sub> = 20mA
Reverse current	I <sub>R</sub>	-	-	10	μA	V <sub>R</sub> = 4V
Input capacitance	C <sub>in</sub>	1	30	250	pF	V = 0, f = 1kHz

Output

Parameter	Symbol	Min.	Тур.*	Max.	Unit	Condition
Collector-Emitter dark current	I <sub>CEO</sub>	-	-	100	nA	V <sub>CE</sub> = 20V, I <sub>F</sub> = 0mA
Collector-Emitter breakdown voltage	BV <sub>CEO</sub>	80	-	-	V	I <sub>C</sub> = 0.1mA
Emitter-Collector breakdown voltage	BV <sub>ECO</sub>	7	-	-	V	I <sub>E</sub> = 0.01mA

Transfer Characteristics (T<sub>a</sub>=25°C unless specified otherwise)

Parameter		Symbol	Min.	Typ.*	Max.	Unit	Condition	
	EL357N	CTR	50	-	600	%		
	EL357NA		80	-	160			
	EL357NB		130	-	260		I <sub>F</sub> = 5mA ,V <sub>CE</sub> = 5V	
Current Transfer ratio	EL357NC		200	-	400			
	EL357ND		300	-	600			
	EL357NE		100	-	200			
	EL357NF		150	-	300			
Collector-Emitter saturation voltage		V <sub>CE(sat)</sub>	-	0.1	0.2	٧	I <sub>F</sub> = 20mA ,I <sub>C</sub> = 1mA	
Isolation resistance		R <sub>IO</sub>	5×10 <sup>10</sup>	-	-	Ω	V <sub>IO</sub> = 500Vdc, 40~60% R.H.	
Floating capac	itance	C <sub>IO</sub>	-	0.6	1.0	pF	V <sub>IO</sub> = 0, f = 1MHz	
Cut-off frequency		fc	-	80	-	kHz	$V_{CE}$ = 5V, $I_C$ = 2mA $R_L$ = 100 $\Omega$ , -3dB	
Rise time		t <sub>r</sub>	-	3	18	μs	$V_{CE} = 2V$ , $I_C = 2mA$ ,	
Fall time		t <sub>f</sub>	-	4	18	μs	$R_L = 100\Omega$	

<sup>\*</sup> Typical values at T<sub>a</sub> = 25°C



### **EL357N-G Series**

### **Typical Performance Curves**

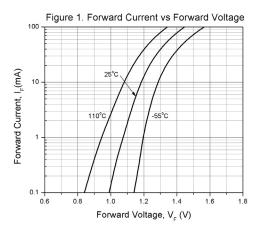
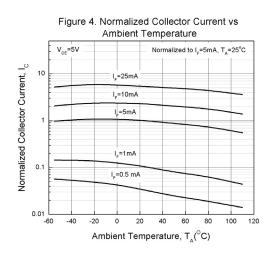
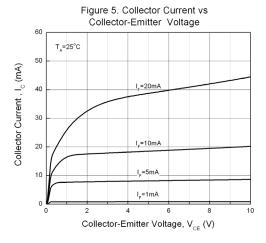
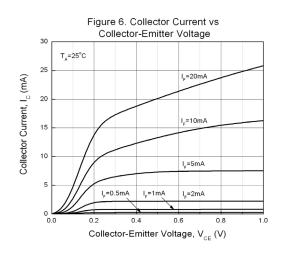


Figure 2. Normalized Collector Current vs Forward Current Normalized Collector Current, I<sub>c</sub> Normalized to I<sub>E</sub>=5mA,V Forward Current,  $I_F$  (mA)

Figure 3. Normalized Current Transfer Ratio vs Forward Current Normalized Current Transfer Ratio, CTR Normalized to I<sub>F</sub>=5mA,V<sub>CE</sub>=5V T\_=25°C V<sub>cE</sub>=10V Forward Current, IF (mA)

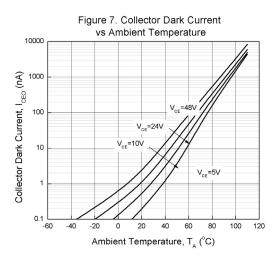


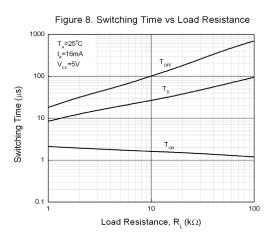


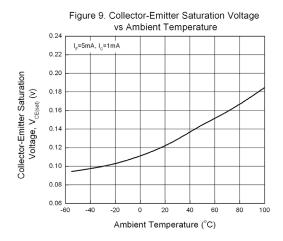




### **EL357N-G Series**







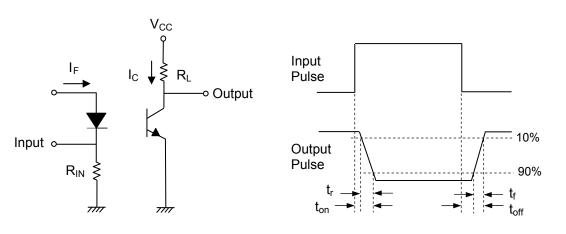


Figure 10. Switching Time Test Circuit & Waveforms



### **EL357N-G Series**

### **Order Information**

**Part Number** 

### EL357NX(Y)-VG

Note

357N = Part No.

X = CTR Rank (A, B, C, D, E, For none) Y = Tape and reel option (TA, TB or none).

V = VDE (optional) G = Halogen free

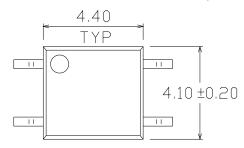
Option	Description	Packing quantity
None	Standard SMD option	100 units per tube
-V	Standard SMD option + VDE	100 units per tube
(TA)	TA Tape & reel option	3000 units per reel
(TB)	TB Tape & reel option	3000 units per reel
(TA)-V	TA Tape & reel option + VDE	3000 units per reel
(TB)-V	TB Tape & reel option + VDE	3000 units per reel

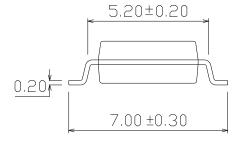


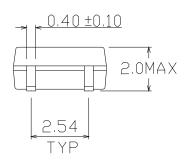
### **EL357N-G Series**

### **Package Drawing**

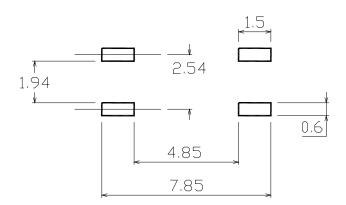
(Dimensions in mm)







### Recommended pad layout for surface mount leadform





### **EL357N-G Series**

### **Device Marking**



#### **Notes**

EL denotes Everlight 357N denotes Device Number

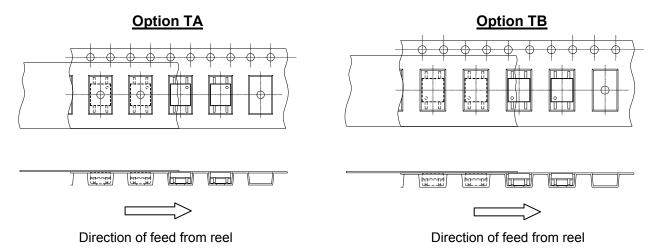
R denotes CTR Rank (A, B, C, D, E, F or none)

Y denotes 1 digit Year code WW denotes 2 digit Week code V denotes VDE (optional)

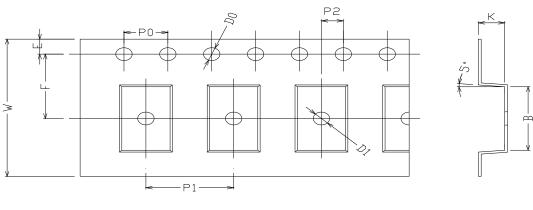


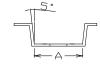
### **EL357N-G Series**

### **Tape & Reel Packing Specifications**



### **Tape dimensions**



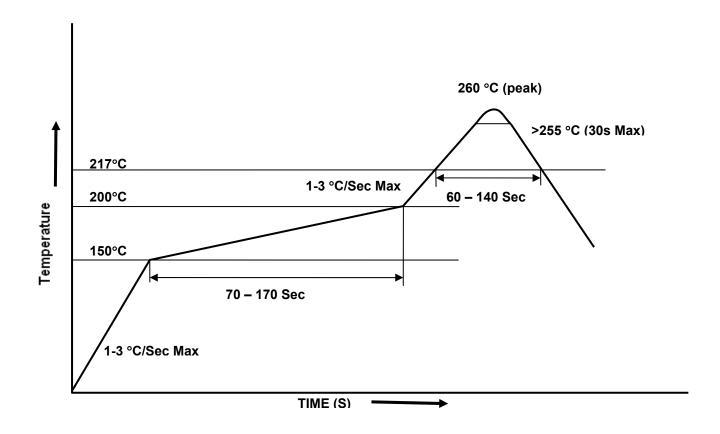


Dimension No.	Α	В	Do	D1	E	F
Dimension (mm)	4.4 ± 0.1	7.4 ± 0.1	1.5 + 0.1/-0	1.5 ± 0.1	1.7 5± 0.1	7.5 ± 0.1
Dimension No.	Po	P1	P2	t	W	K



### **EL357N-G Series**

### **Solder Reflow Temperature Profile**





### **EL357N-G Series**

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